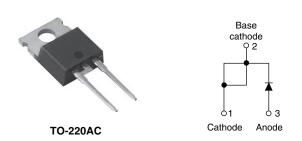


VS-MBR16...PbF Series, VS-MBR16...-N3 Series

www.vishay.com

Vishay Semiconductors

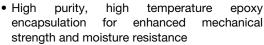
High Performance Schottky Rectifier, 16 A



PRODUCT SUMMARY					
Package	TO-220AC				
I _{F(AV)}	16 A				
V_{R}	35 V, 45 V				
V _F at I _F	0.57 V				
I _{RM} max.	40 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	24 mJ				

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBR16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform		16	Α		
V_{RRM}			35, 45	V		
I _{FSM}	$t_p = 5 \mu s sine$		1800	Α		
V _F	16 A _{pk} , T _J = 125 °C		0.57	V		
TJ	Range		-65 to +150	°C		

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-MBR1635PbF	VS-MBR1635-N3	VS-MBR1645PbF	VS-MBR1645-N3	UNITS	
Maximum DC reverse voltage	V_R						
Maximum working peak reverse voltage	V_{RWM}	35	35	45	45	V	

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CON	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T_C = 134 °C, rated V_R	16	Α			
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied				
	T GIVI	Surge applied at rated load condition half wave single phase, 60 Hz		150			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}$, $I_{AS} = 3.6 \text{A}$, $L = 3.7 \text{mH}$		24	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.6	А		



VS-MBR16...PbF Series, VS-MBR16...-N3 Series

www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
Maximum fanuard valtage drap	V _{FM} ⁽¹⁾	16 A	T _J = 25 °C	0.63	V	
Maximum forward voltage drop	V _{FM} (1)	10 A	T _J = 125 °C	0.57	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA	
Maximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	40		
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		1400	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

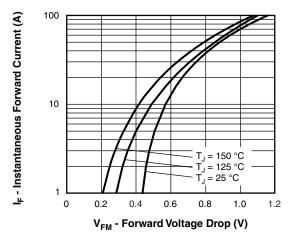
Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		-65 to +150	°C		
Maximum storage temperature range	T _{Stg}	T _{Stg}		10		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.50	°C/W		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased		O/VV		
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Mounting torque minimum			6 (5)	kgf ⋅ cm		
maximum			12 (10)	(lbf \cdot in)		
Marking daving		Coop obulo TO 220AC (JEDEC)	MBR	1635		
Marking device		Case style TO-220AC (JEDEC)		MBR1645		

www.vishay.com

Vishay Semiconductors



100 T_J = 150 °C I_R - Reverse Current (µA) 10 T_J = 125 °C T. = 100 °C 0.1 T_J = 75 °C T_{.1} = 50 °C 0.01 = 25 °C 0.001 0.0001 0 5 15 25 40 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

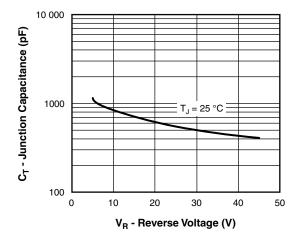


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

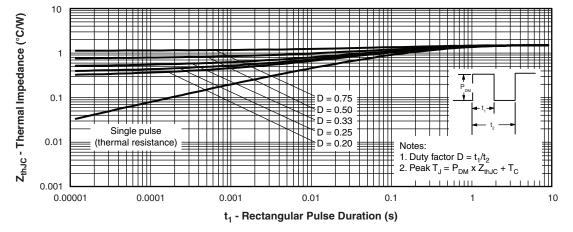


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



www.vishay.com

Vishay Semiconductors

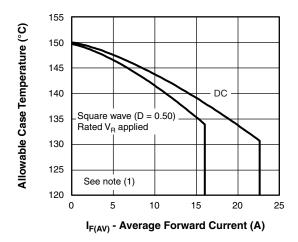


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

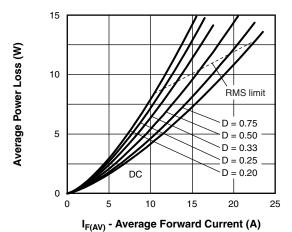


Fig. 6 - Forward Power Loss Characteristics

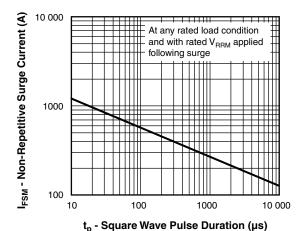


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

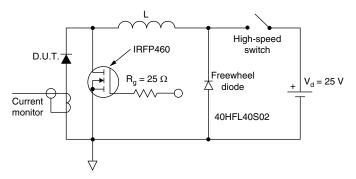


Fig. 8 - Unclamped Inductive Test Circuit

Note

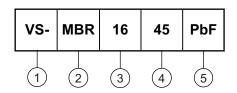
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = & \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = & \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \text{ applied} \\ \end{array}$

VS-MBR16...PbF Series, VS-MBR16...-N3 Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

Current rating (16 = 16 A)

35 = 35 V 45 = 45 V

5 - Environmental digit

• PbF = lead (Pb)-free and RoHS-compliant

• -N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MBR1635PbF	50	1000	Antistatic plastic tube				
VS-MBR1635-N3	50	1000	Antistatic plastic tube				
VS-MBR1645PbF	50	1000	Antistatic plastic tube				
VS-MBR1645-N3	50	1000	Antistatic plastic tube				

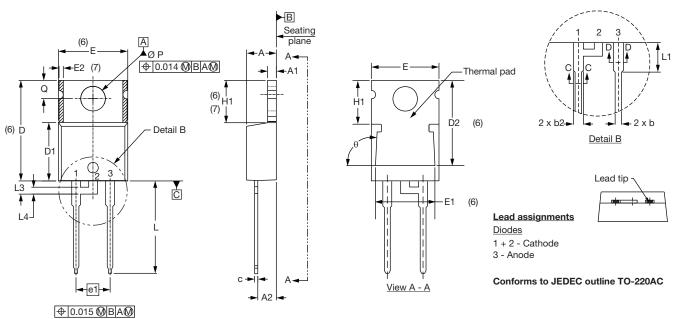
LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95221				
Dort marking information	TO-220AC PbF	www.vishay.com/doc?95224				
Part marking information	TO-220AC -N3	www.vishay.com/doc?95068				



Vishay Semiconductors

TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 13-Jun-16 1 Document Number: 91000